

FORM: PTO-1449 (REV: 7-80)	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	Atty Docket No: 2000-0116.01/US	Serial No: 10/787,225
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (37 CFR 1.98(b))		Applicant: Kelly T. Hurley	
		Filing Date: February 26, 2004	Group: 2822
(use several sheets if necessary)			

U.S. PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Name	Class	Subclass
JM	AA 6,271,087	08/07/2001	Kinoshita et al.	438	258
	AB 6,188,115	02/13/2001	Kamitani	257	412
	AC 6,080,624	06/27/2000	Kamiya et al.	438	257
	AD 5,994,733	11/30/1999	Nishioka et al.	257	316
	AE 5,731,242	03/24/1998	Parat et al.	438	586
JM	AF 5,210,047	05/11/1993	Woo et al.	437	43
AG					
AH					
AI					
AJ					
AK					

FOREIGN PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Country	Class	Subclass	Translation Yes	Translation No
	AL					<input type="checkbox"/>	<input type="checkbox"/>
	AM					<input type="checkbox"/>	<input type="checkbox"/>
	AN					<input type="checkbox"/>	<input type="checkbox"/>
	AO					<input type="checkbox"/>	<input type="checkbox"/>
	AP					<input type="checkbox"/>	<input type="checkbox"/>
	AQ					<input type="checkbox"/>	<input type="checkbox"/>

Initial

OTHER ART (including author, title, date, pertinent pages, etc.)

JM	AR		"A 130-mm ² , 256-Mbit NAND Flash with Shallow Trench Isolation Technology", Kenichi Imamiya et al., IEEE Journal of Solid-State Circuits, Vol. 34, No. 11, November 1999
JM	AS		"Novel 0.44μm ² Ti-Salicide STI Cell Technology for High Density NOR Flash Memories and High Performance Embedded Application", H. Watanabe et al., IEDM 98, pp. 975-978
	AT		

Examiner:

T. M. Thomas

Date Considered:

10-03-05

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP §609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication with applicant.